Single and Dual Low Voltage, Rail-to-Rail Input and Output, Operational Amplifiers

The LMV931 Single and LMV932 Dual are CMOS low-voltage operational amplifiers which can operate on single-sided power supplies (1.8 V to 5.0 V) with rail-to-rail input and output swing. Both devices come in small state-of-the-art packages and require very low quiescent current making them ideal for battery-operated, portable applications such as notebook computers and hand-held instruments. Rail-to-Rail operation provides improved signal-to-noise performance plus the small packages allow for closer placement to signal sources thereby reducing noise pickup.

The single LMV931 is offered in space saving SC70–5 package. The dual LMV932 is in either a Micro8 or SOIC package. These small packages are very beneficial for crowded PCB's.

Features

- Performance Specified on Single-Sided Power Supply: 1.8 V, 2.7 V, and 5 V
- Small Packages:

LMV931 in a SC-70 LMV932 in a Micro8 or SOIC-8

- No Output Crossover Distortion
- Extended Industrial Temperature Range: -40°C to +125°C
- Low Quiescent Current 210 μA, Max Per Channel
- No Output Phase-Reversal from Overdriven Input
- These are Pb-Free Devices

Typical Applications

- Notebook Computers, Portable Battery-Operated Instruments, PDA's
- Active Filters, Low-Side Current Monitoring

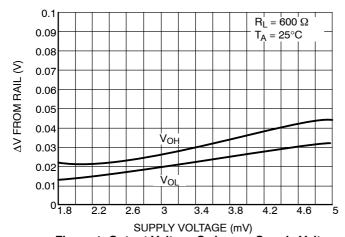


Figure 1. Output Voltage Swing vs. Supply Voltage



ON Semiconductor®

http://onsemi.com

MARKING DIAGRAMS

LMV931 (Single)



SC-70 CASE 419A





TSOP-5 CASE 483



M = Date Code

■ = Pb-Free Package

(*Note: Microdot may be in either location)

LMV932 (Dual)



Micro8[™] CASE 846A





SOIC-8 CASE 751



A = Assembly Location

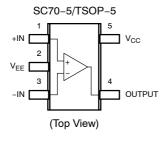
Y = Year
L = Wafer Lot
W = Work Week
■ Pb-Free Package

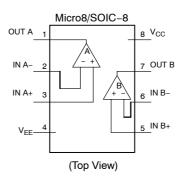
(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 14 of this data sheet.

PIN CONNECTIONS





MAXIMUM RATINGS

Symbol	Rating		Value	Unit
Vs	Supply Voltage (Operating Range V _S = 1.8 V to 5.5 V)	5.5	V	
V_{IDR}	Input Differential Voltage		± Supply Voltage	V
V _{ICR}	Input Common Mode Voltage Range		-0.5 to (V _{CC}) + 0.5	V
	Maximum Input Current		10	mA
t _{So}	Output Short Circuit (Note 1)		Continuous	
T_J	Maximum Junction Temperature (Operating Range -40°C to	85°C)	150	°C
$\theta_{\sf JA}$	Thermal Resistance:	SC-70 TSOP-5 Micro8	280 333 238	°C/W
T _{stg}	Storage Temperature		-65 to 150	°C
	Mounting Temperature (Infrared or Convection ≤ 30 sec)		260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ESD data available upon request.

 Continuous short-circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45 mA over long term may adversely affect reliability. Shorting output to either V_{CC} or V_{EE} will adversely affect reliability.

1.8 V DC ELECTRICAL CHARACTERISTICS (Note 2) Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, $V_S = 1.8$ V, $V_{CM} = V_S/2$, $V_O = V_S/2$ and $R_L > 1$ M Ω . Typical specifications represent the most likely parametric norm.

Parameter	,		Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	LMV931 (Single) (-40°C to +125°C)		1	6	mV
		LMV932 (Dual) (-40°C to +125°C)		1	7.5	
Input Offset Voltage Average Drift	TCV _{IO}			5.5		μV/°C
Input Bias Current	Ι _Β	−40°C to +125°C		< 1		nA
Input Offset Current	I _{IO}	-40°C to +125°C		< 1		nA
Supply Current	I _{CC}	In Active Mode		75	185	μΑ
(per Channel)		-40°C to +125°C			205	
Common Mode	CMRR	$0 \text{ V} \le \text{V}_{\text{CM}} \le 0.6 \text{ V}, 1.4 \text{ V} \le \text{V}_{\text{CM}} \le 1.8 \text{ V}$	50	70		dB
Rejection Ratio		– 40°C to +125°C	50			
		$-0.2 \text{ V} \leq \text{ V}_{\text{CM}} \leq 0 \text{ V}, 1.8 \text{ V} \leq \text{ V}_{\text{CM}} \leq 2 \text{ V}$	50	70		
Power Supply	PSRR	$1.8 \text{ V} \le \text{V}^+ \le 5 \text{ V}, \text{V}_{\text{CM}} = 0.5 \text{ V}$	50	70		dB
Rejection Ratio		-40°C to +125°C	50			
Input Common–Mode Voltage Range	Vсм	For CMRR ≥ 50 dB and T _A = 25°C	V _{EE} - 0.2	-0.2 to 2.1	V _{CC} + 0.2	V
		For CMRR ≥ 50 dB and T _A = - 40°C to +85°C	V _{EE}		V _{CC}	
		For CMRR \geq 50 dB and T _A = -40° C to $+125^{\circ}$ C	V _{EE} + 0.2		V _{CC} - 0.2	
Large Signal Voltage	A_V	R_L = 600 Ω to 0.9 V, V_O = 0.2 V to 1.6 V, V_{CM} = 0.5 V	77	101		dB
Gain LMV931 (Single)		-40°C to +125°C	73			
		R_L = 2 k Ω to 0.9V, V_O = 0.2 V to 1.6 V, V_{CM} = 0.5 V	80	105		
		-40°C to +125°C	75			
Large Signal Voltage	1	R_L = 600 Ω to 0.9 V, V_O = 0.2 V to 1.6 V, V_{CM} = 0.5 V	75	90		
Gain LMV932 (Dual)		-40°C to +125°C	72			
		R_L = 2 k Ω to 0.9 V, V_O = 0.2 V to 1.6 V, V_{CM} = 0.5 V	78	100		
		-40°C to +125°C	75			
Output Swing	V _{OH}	R_L = 600 Ω to 0.9V, V_{IN} = \pm 100 mV	1.65	1.72		V
		-40°C to +125°C	1.63			
	V _{OL}	R_L = 600 Ω to 0.9V, V_{IN} = \pm 100 mV		0.077	0.105	
		-40°C to +125°C			0.12	
	V _{OH}	R_L = 2 k Ω to 0.9V, V_{IN} = \pm 100 mV	1.75	1.77		
		-40°C to +125°C	1.74			
	V _{OL}	R _L = 2 kΩ to 0.9 V, V _{IN} = \pm 100 mV		0.24	0.035	
		-40°C to +125°C			0.04	
Output Short Circuit	I _O	Sourcing, Vo = 0 V, V _{IN} = +100 mV	4.0	30		mA
Current		-40°C to +125°C	3.3			
		Sinking, Vo = 1.8V, V _{IN} = -100 mV	7.0	60		
		−40°C to +125°C	5.0			

^{2.} Guaranteed by design and/or characterization.

1.8 V AC ELECTRICAL CHARACTERISTICS Unless otherwise specified, all limits are guaranteed for $T_A = 25$ °C, $V_S = 1.8$ V, $V_{CM} = V_S/2$, $V_0 = V_S/2$ and $R_L > 1$ M Ω . Typical specifications represent the most likely parametric norm. Min/Max specifications are guaranteed by testing, characterization, or statistical analysis.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Slew Rate	SR	(Note 3)		0.35		V/μS
Gain Bandwidth Product	GBWP			1.4		MHz
Phase Margin	Θm			67		0
Gain Margin	Gm			7		dB
Input-Referred Voltage Noise	e _n	f = 50 kHz, V _{CM} = 0.5 V		60		nV/√ Hz
Total Harmonic Distortion	THD	f = 1 kHz, A_V = +1, R_L = 600 Ω , V_O = 1 V_{PP}		0.023		%
Amplifier-to-Amplifier Isolation		(Note 4)		123		dB

^{3.} Connected as voltage follower with input step from V_{EE} to V_{CC} . Number specified is the slower of the positive and negative slew rates. 4. Input referred, $R_L = 100 \text{ k}\Omega$ connected to $V_S/2$. Each amp excited in turn with 1 kHz to produce $V_O = 3 \text{ V}_{PP}$. (For Supply Voltages < 3 V,

2.7 V DC ELECTRICAL CHARACTERISTICS (Note 5) Unless otherwise noted, all min/max limits are guaranteed for T_A = 25°C, V_S = 2.7 V, V_{CM} = $V_S/2$, V_O = $V_S/2$ and R_L > 1 M Ω . Typical specifications represent the most likely parametric norm.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	LMV931 (Single) (-40°C to +125°C)		1	6	mV
		LMV932 (Dual) (-40°C to +125°C)		1	7.5	
Input Offset Voltage Average Drift	TCV _{IO}			5.5		μV/°C
Input Bias Current	Ι _Β	−40°C to +125°C		< 1		nA
Input Offset Current	I _{IO}	−40°C to +125°C		< 1		nA
Supply Current (per	I _{CC}	In Active Mode		80	190	μΑ
Channel)		−40°C to +125°C			210	
Common Mode	CMRR	0 V \leq V _{CM} \leq 1.5 V, 2.3 V \leq V _{CM} \leq 2.7 V	50	70		dB
Rejection Ratio	-	−40°C to +125°C	50			
	-	$-0.2 \text{ V} \leq \text{V}_{\text{CM}} \leq 0 \text{ V}, 2.7 \text{ V} \leq \text{V}_{\text{CM}} \leq 2.9 \text{ V}$	50	70		
Power Supply	PSRR	$1.8~V \leq V^{+} \leq 5~V, V_{CM} = 0.5~V$	50	70		dB
Rejection Ratio	-	−40°C to +125°C	50			
Input Common-Mode Voltage Range	Vсм	For CMRR \geq 50 dB and T _A = 25°C	V _{EE} - 0.2	-0.2 to 3.0	V _{CC} + 0.2	V
	-	For CMRR \geq 50 dB and T _A = -40°C to +85°C	V _{EE}		V _{CC}	
		For CMRR \geq 50 dB and $T_A = -40^{\circ}C$ to $+125^{\circ}C$	V _{EE} + 0.2		V _{CC} - 0.2	
Large Signal Voltage	A_V	R_L = 600 Ω to 1.35 V, V_O = 0.2 V to 2.5 V	87	104		dB
Gain LMV931 (Single)		−40°C to +125°C	86			
		R_L = 2 k Ω to 1.35 V, V_O = 0.2 V to 2.5 V	92	110		
	-	−40°C to +125°C	91			
Large Signal Voltage	A_V	R_L = 600 Ω to 1.35 V, V_O = 0.2 V to 2.5 V	78	90		
Gain LMV932 (Dual)		−40°C to +125°C	75			
	-	$R_L = 2~k\Omega$ to 1.35 V, V_O = 0.2 V to 2.5 V	81	100		
		−40°C to +125°C	78			
Output Swing	V _{OH}	R_L = 600 Ω to 1.35 V, V_{IN} = ±100 mV	2.55	2.62		V
		−40°C to +125°C	2.53			
	V _{OL}	R_L = 600 Ω to 1.35 V, V_{IN} = ±100 mV		0.083	0.11	
		−40°C to +125°C			0.13	
	V _{OH}	R_L = 2 k Ω to 1.35 V, V_{IN} = $\pm100~mV$	2.65	2.675		
		−40°C to +125°C	2.64			
	V _{OL}	R_L = 2 k Ω to 1.35 V, V_{IN} = ±100 mV		0.025	0.04	
		-40°C to +125°C			0.045	
Output Short Circuit	I _O	Sourcing, Vo = 0 V, $V_{IN} = \pm 100 \text{ mV}$	20	65		mA
Current		-40°C to +125°C	15			
		Sinking, Vo = 0 V, $V_{IN} = -100 \text{ mV}$	18	75		
		-40°C to +125°C	12			

^{5.} Guaranteed by design and/or characterization.

2.7 V AC ELECTRICAL CHARACTERISTICS Unless otherwise specified, all limits are guaranteed for $T_A = 25$ °C, $V_S = 2.7$ V, $V_{CM} = V_S/2$, $V_O = V_S/2$ and $R_L > 1$ M Ω . Typical specifications represent the most likely parametric norm. Min/Max specifications are guaranteed by testing, characterization, or statistical analysis.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Slew Rate	SR	(Note 6)		0.4		V/uS
Gain Bandwidth Product	GBWP			1.4		MHz
Phase Margin	Θm			70		0
Gain Margin	Gm			7.5		dB
Input-Referred Voltage Noise	e _n	f = 50 kHz, V _{CM} = 1.0 V		57		nV/√ Hz
Total Harmonic Distortion	THD	f = 1 kHz, A_V = +1, R_L = 600 Ω , V_O = 1 V_{PP}		0.022		%
Amplifier-to-Amplifier Isolation		(Note 7)		123		dB

^{6.} Connected as voltage follower with input step from V_{EE} to V_{CC} . Number specified is the slower of the positive and negative slew rates.

7. Input referred, $R_L = 100 \text{ k}\Omega$ connected to $V_S/2$. Each amp excited in turn with 1 kHz to produce $V_O = 3 \text{ V}_{PP}$. (For Supply Voltages < 3 V,

5 V DC ELECTRICAL CHARACTERISTICS (Note 8) Unless otherwise noted, all min/max limits are guaranteed for T_A = 25°C, V_S = 5 V, V_{CM} = V_S /2, V_O = V_S /2 and R_L > 1 M Ω . Typical specifications represent the most likely parametric norm.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	LMV931 (Single) (-40°C to +125°C)		1	6	mV
		LMV932 (Dual) (-40°C to +125°C)		1	7.5	
Input Offset Voltage Average Drift	TCV _{IO}			5.5		μV/°C
Input Bias Current	I _B	-40°C to +125°C		< 1		nA
Input Offset Current	I _{IO}	−40°C to +125°C		< 1		nA
Supply Current (per	I _{CC}	In Active Mode		95	210	μΑ
Channel)		−40°C to +125°C			230	
Common-Mode	CMRR	0 V \leq V _{CM} \leq 3.8 V, 4.6 V \leq V _{CM} \leq 5.0 V	50	70		dB
Rejection Ratio		−40°C to +125°C	50			
		$-0.2 \text{ V} \leq \text{V}_{\text{CM}} \leq 0 \text{ V}, 5.0 \text{ V} \leq \text{V}_{\text{CM}} \leq 5.2 \text{V}$	50	70		
Power Supply	PSRR	$1.8 \text{ V} \leq \text{V}^+ \leq 5 \text{ V}, \text{V}_{CM} = 0.5 \text{ V}$	50	70		dB
Rejection Ratio		−40°C to +125°C	50			
Input Common–Mode Voltage Range	Vсм	For CMRR ≥ 50 dB and $T_A = 25^{\circ}C$	V _{EE} - 0.2	-0.2 to 5.3	V _{CC} + 0.2	V
		For CMRR \geq 50 dB and T _A = -40° C to $+85^{\circ}$ C	V _{EE}		V _{CC}	
		For CMRR \geq 50 dB and T _A = -40° C to $+125^{\circ}$ C	V _{EE} + 0.3		V _{CC} - 0.3	
Large Signal Voltage	A _V	R_L = 600 Ω to 2.5 V, V_O = 0.2 V to 4.8 V	88	102		dB
Gain LMV931 (Single)		−40°C to +125°C	87			
		R_L = 2 k Ω to 2.5 V, V_O = 0.2 V to 4.8 V	94	113		
		−40°C to +125°C	93			
Large Signal Voltage	A _V	R_L = 600 Ω to 2.5 V, V_O = 0.2 V to 4.8 V	81	90		
Gain LMV932 (Dual)	Ī	−40°C to +125°C	78			
		R_L = 2 k Ω to 2.5 V, V_O = 0.2 V to 4.8 V	85	100		
		−40°C to +125°C	82			
Output Swing	V _{OH}	R_L = 600 Ω to 2.5 V, V_{IN} = \pm 100 mV	4.855	4.89		V
		−40°C to +125°C	4.835			
	V _{OL}	R_L = 600 Ω to 2.5 V, V_{IN} = ±100 mV		0.12	0.16	
		−40°C to +125°C			0.18	
	V _{OH}	R_L = 2 k Ω to 2.5 V, V_{IN} = ± 100 mV	4.945	4.967		
		−40°C to +125°C	4.935			
	V _{OL}	R_L = 2 k Ω to 2.5 V, V_{IN} = ±100 mV		0.037	0.065	
		-40°C to +125°C			0.075	
Output Short-Circuit	I _O	Sourcing, Vo = 0 V, V_{IN} = +100 mV	55	65		mA
Current		-40°C to +125°C	45			
		Sinking, Vo = 5 V, V _{IN} = -100 mV	58	80		
		-40°C to +125°C	45			

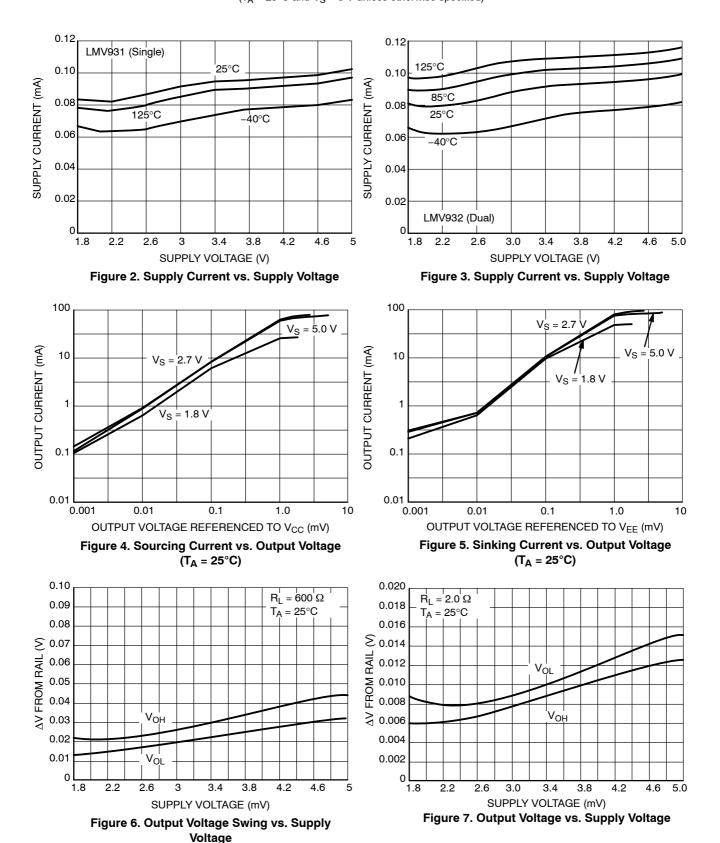
^{8.} Guaranteed by design and/or characterization.

5 V AC ELECTRICAL CHARACTERISTICS Unless otherwise specified, all limits are guaranteed for T_A = 25°C, V_S = 5 V, V_{CM} = $V_S/2$, V_O = $V_S/2$ and R_L > 1 $M\Omega$. Typical specifications represent the most likely parametric norm.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Slew Rate	SR	(Note 9)		0.48		V/uS
Gain Bandwidth Product	GBWP			1.5		MHz
Phase Margin	Θm			65		0
Gain Margin	Gm			8		dB
Input-Referred Voltage Noise	e _n	f = 50 kHz, V _{CM} = 2 V		50		nV/√ Hz
Total Harmonic Distortion	THD	f = 1 kHz, A_V = +1, R_L = 600 Ω , V_O = 1 V_{PP}		0.022		%
Amplifier-to- Amplifier Isolation		(Note 10)		123		dB

^{9.} Connected as voltage follower with input step from V_{EE} to V_{CC} . Number specified is the slower of the positive and negative slew rates. 10. Input referred, R_L = 100 k Ω connected to $V_S/2$. Each amp excited in turn with 1 kHz to produce V_O = 3 V_{PP} . (For Supply Voltages < 3 V, V_O = V_{CC}).

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

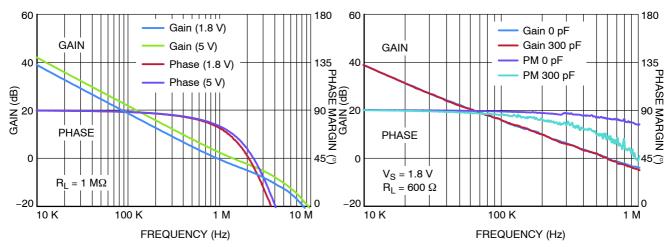


Figure 8. Open Loop Gain and Phase

Figure 9. Frequency Response vs. CL

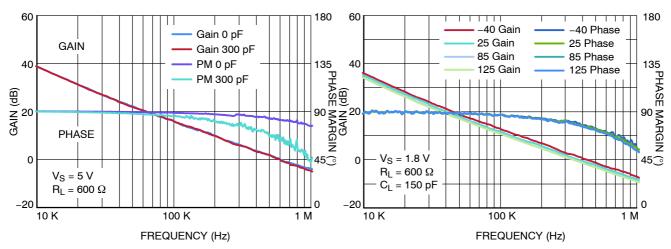


Figure 10. Frequency Response vs. CL

Figure 11. Gain and Phase vs. Temp

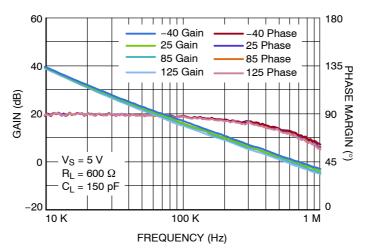


Figure 12. Gain and Phase vs. Temp

TYPICAL CHARACTERISTICS

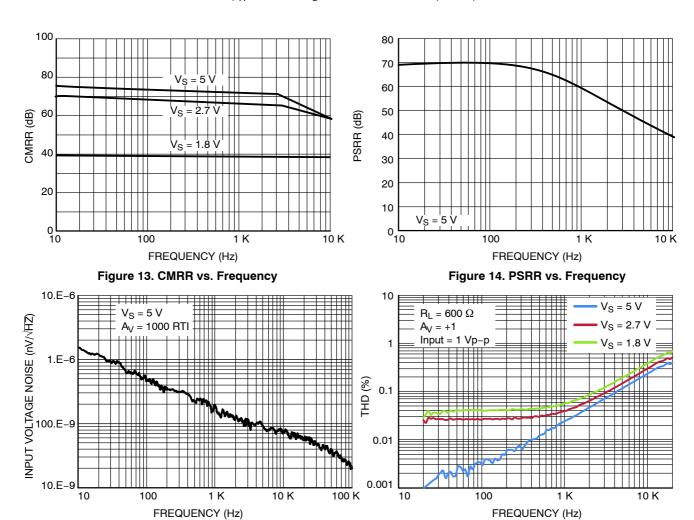


Figure 15. Input Voltage Noise vs. Frequency

Figure 16. THD vs. Frequency

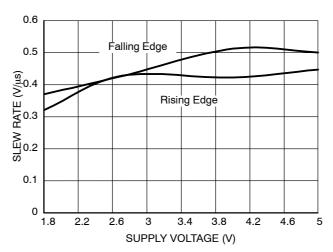


Figure 17. Slew Rate vs. Supply Voltage

TYPICAL CHARACTERISTICS

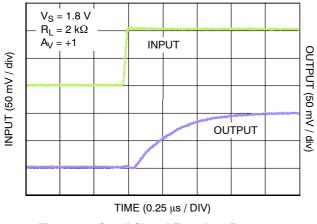


Figure 18. Small Signal Transient Response

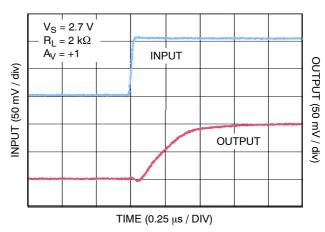


Figure 19. Small Signal Transient Response

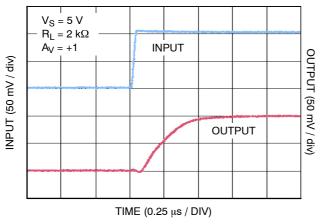


Figure 20. Small Signal Transient Response

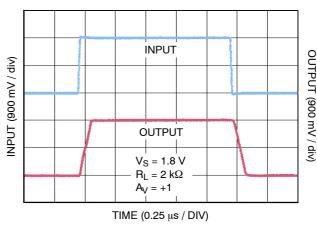


Figure 21. Large Signal Transient Response

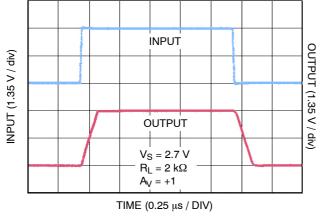


Figure 22. Large Signal Transient Response

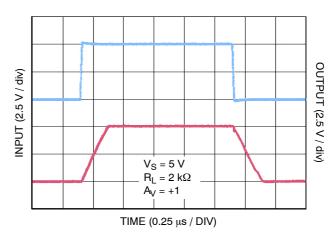
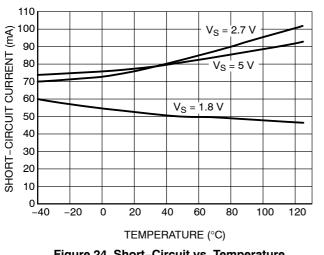


Figure 23. Large Signal Transient Response

TYPICAL CHARACTERISTICS

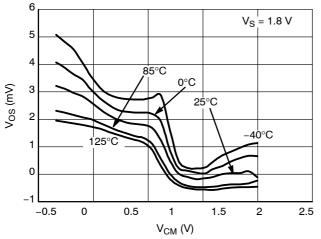
 $(T_A = 25^{\circ}C \text{ and } V_S = 5 \text{ V unless otherwise specified})$



110 100 SHORT-CIRCUIT CURRENT (mA) 90 V_S = 5 V 80 70 $V_{S} = 2.7 \text{ V}$ 60 50 40 30 20 V_S = 1.8 V 10 -20 -40 60 80 100 120 TEMPERATURE (°C)

Figure 24. Short-Circuit vs. Temperature (Sinking)

Figure 25. Short-Circuit vs. Temperature (Sourcing)



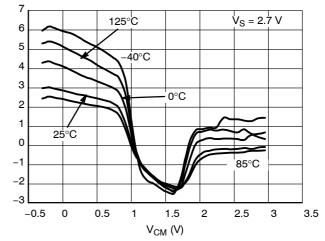
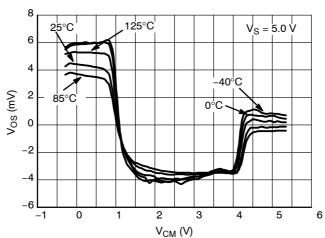


Figure 26. Offset Voltage vs. Common Mode Range V_{DD}

Figure 27. Offset Voltage vs. Common Mode Range



Vos (mV)

Figure 28. Offset Voltage vs. Common Mode Range

APPLICATION INFORMATION

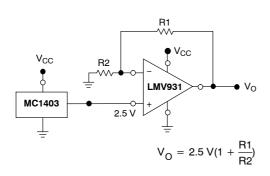


Figure 29. Voltage Reference

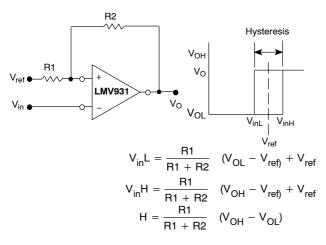


Figure 31. Comparator with Hysteresis

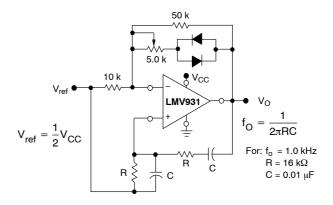
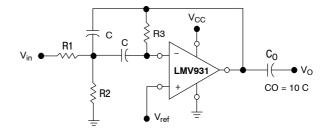


Figure 30. Wien Bridge Oscillator



Given: f_0 = center frequency $A(f_0)$ = gain at center frequency

Choose value f_o , $\frac{C}{Q}$ Then: $R3 = \frac{Q}{\pi f_O C}$ $R1 = \frac{R3}{2 \text{ A(f}_O)}$ $R2 = \frac{R1 \text{ R3}}{4Q^2 \text{ R1} - R3}$

For less than 10% error from operational amplifier, (($Q_O f_O$)/BW) < 0.1 where f_O and BW are expressed in Hz. If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 32. Multiple Feedback Bandpass Filter

ORDERING INFORMATION

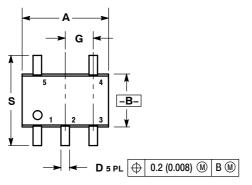
Order Number	Number of Channels	Number of Pins	Package Type	Shipping [†]
LMV931SQ3T2G	Single	5	SC70-5 (Pb-Free)	3000 / Tape & Reel
LMV931SN3T1G	Single	5	TSOP-5 (Pb-Free)	3000 / Tape & Reel
LMV932DMR2G*	Dual	8	Micro8 (Pb-Free)	4000 / Tape & Reel
LMV932DR2G	Dual	8	SOIC-8 (Pb-Free)	2500 / Tape & Reel

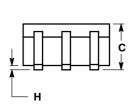
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

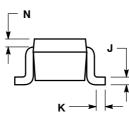
^{*}Consult Sales.

PACKAGE DIMENSIONS

SC-88A, SOT-353, SC-70 CASE 419A-02 **ISSUE J**





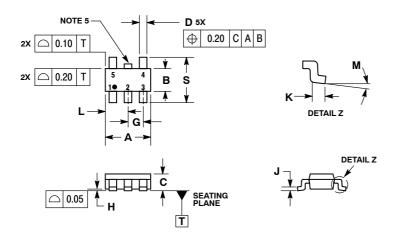


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65	BSC
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008	REF	0.20	REF
S	0.079	0.087	2 00	2 20

PACKAGE DIMENSIONS

TSOP-5 CASE 483-02 **ISSUE H**



NOTES:

- NOTES:

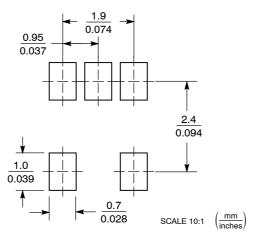
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS. 3 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIA
- OF BASE MATERIAL.

 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE
- MOLD FLOATH, FRO TROSIONS, OR GATE BURRS. 5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

	MILLIN	IETERS
DIM	MIN	MAX
Α	3.00	BSC
В	1.50	BSC
С	0.90	1.10
D	0.25	0.50
G	0.95	BSC
Н	0.01	0.10
J	0.10	0.26
K	0.20	0.60
L	1.25	1.55
М	0 °	10 °
۰.	2.50	3 00

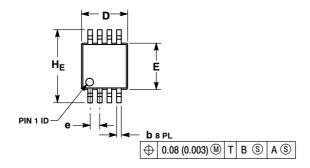
SOLDERING FOOTPRINT*

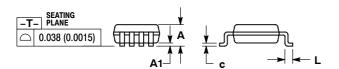


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

Micro8™ CASE 846A-02 **ISSUE H**

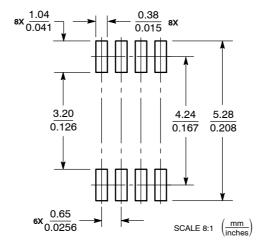




- IES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE
 BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED
- MOLD FLASH, PROTROSIONS ON GATE BURNS SHALL NOT EACEED
 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 846A-01 OBSOLETE, NEW STANDARD 846A-02.

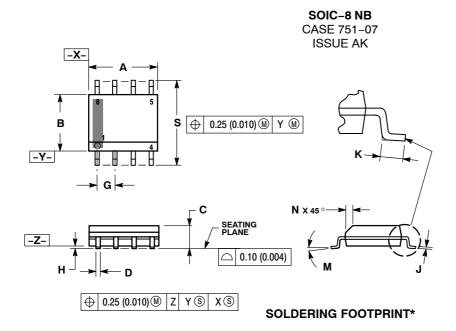
	М	ILLIMETE	RS	INCHES		
DIM	MIN	NOM	MAX	MIN	MON	MAX
Α			1.10			0.043
A1	0.05	0.08	0.15	0.002	0.003	0.006
b	0.25	0.33	0.40	0.010	0.013	0.016
С	0.13	0.18	0.23	0.005	0.007	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	2.90	3.00	3.10	0.114	0.118	0.122
е		0.65 BSC		0.026 BSC		
L	0.40	0.55	0.70	0.016	0.021	0.028
HE	4.75	4.90	5.05	0.187	0.193	0.199

SOLDERING FOOTPRINT*



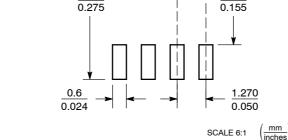
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A AND B DO NOT INCLUDE
 MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 751–01 THRU 751–06 ARE OBSOLETE. NEW STANDARD IS 751–07.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.197
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27	7 BSC	0.05	0 BSC
Н	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
М	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244



7.0

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

1.52 0.060

4.0

Micro8 is a trademark of International Rectifier.

ON Semiconductor and was are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking, ited. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada

Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center

Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

AMEYA360 Components Supply Platform

Authorized Distribution Brand:

























Website:

Welcome to visit www.ameya360.com

Contact Us:

> Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

> Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

Customer Service :

Email service@ameya360.com

Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com